

JAN2N6796

Request a Quote

JAN2N6796 Information

Heisener.com	Part Number	JAN2N6796
	Manufacturer	Microsemi Corporation
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH TO-205AF TO-39
	Package	TO-205AF Metal Can
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N6796 Specifications

Manufacturer Part Number	JAN2N6796
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-205AF Metal Can
Series	Military, MIL-PRF-19500/557
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	28.51nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	800mW (Ta), 25W (Tc)
Rds On (Max) @ Id, Vgs	195 mOhm @ 8A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-39
Package / Case	TO-205AF Metal Can
	Report errors?

JAN2N6796 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N6796, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com